

RELIABILITY REPORT
FOR
MAX14626ETT+T
PLASTIC ENCAPSULATED DEVICES

June 7, 2013

MAXIM INTEGRATED

160 RIO ROBLES
SAN JOSE, CA 95134

Approved by
Richard Aburano
Quality Assurance
Manager, Reliability Engineering

Conclusion

The MAX14626ETT+T successfully meets the quality and reliability standards required of all Maxim Integrated products. In addition, Maxim Integrated's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim Integrated's quality and reliability standards.

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I. Device Description**A. General**

The MAX14626 current loop protector features a current-limit switch to prevent damage to the analog input module from sensor failure. The current-limit switch features a 25Ω (typ) on-resistance and operates from a +2.3V to +36V input voltage range. The accurate current limit is set to 30mA, making the part ideal for protecting the sensor reading devices. The MAX14626 handles an overcurrent event in a continuous current-limit mode. Additional safety features include thermal shutdown to prevent overheating and reverse-input blocking to protect from being reverse connected into the sensor. The device is available in a tiny 6-pin (3mm x 3mm), TDFN exposed pad package and is specified over the -40°C to +85°C extended temperature range.

II. Manufacturing Information

A. Description/Function:	High-Voltage Reverse-Input-Capable 4â€"20mA Current Loop Protector
B. Process:	S18
C. Number of Device Transistors:	3272
D. Fabrication Location:	USA
E. Assembly Location:	Taiwan and Thailand
F. Date of Initial Production:	March 30, 2012

III. Packaging Information

A. Package Type:	6-pin TDFN 3x3
B. Lead Frame:	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive
E. Bondwire:	Au (1 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#05-9000-4868
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C	Level 1
J. Single Layer Theta Ja:	55°C/W
K. Single Layer Theta Jc:	9°C/W
L. Multi Layer Theta Ja:	42°C/W
M. Multi Layer Theta Jc:	9°C/W

IV. Die Information

A. Dimensions:	25.5905X37.7953 mils
B. Passivation:	Si ₃ N ₄ /SiO ₂ (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Al/0.5%Cu with Ti/TiN Barrier
D. Backside Metallization:	None
E. Minimum Metal Width:	0.23 microns (as drawn)
F. Minimum Metal Spacing:	0.23 microns (as drawn)
G. Bondpad Dimensions:	
H. Isolation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw

V. Quality Assurance Information

- A. Quality Assurance Contacts: Richard Aburano (Manager, Reliability Engineering)
Don Lipps (Manager, Reliability Engineering)
Bryan Preeshl (Vice President of QA)
- B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.
0.1% For all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4340 \times 48 \times 2} \quad (\text{Chi square value for MTTF upper limit})$$

(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$\lambda = 22.9 \times 10^{-9}$$

$$\lambda = 22.9 \text{ F.I.T. (60\% confidence level @ 25°C)}$$

The following failure rate represents data collected from Maxim Integrated's reliability monitor program. Maxim Integrated performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at <http://www.maximintegrated.com/qa/reliability/monitor>. Cumulative monitor data for the S18 Process results in a FIT Rate of 0.05 @ 25C and 0.93 @ 55C (0.8 eV, 60% UCL)

B. E.S.D. and Latch-Up Testing (lot SACV9Q001C, D/C 1152)

The AL43-0 die type has been found to have all pins able to withstand a HBM transient pulse of +/- 2500V per JEDEC JESD22-A114. Latch-Up testing has shown that this device withstands a current of +/- 100mA and overvoltage per JEDEC JESD78.

Table 1
Reliability Evaluation Test Results

MAX14626ETT+T

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	COMMENTS
Static Life Test (Note 1)	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality	48	0	SACV9Q001C, D/C 1152

Note 1: Life Test Data may represent plastic DIP qualification lots.